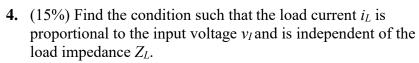
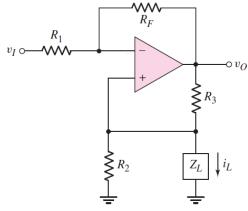
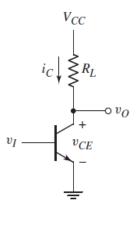
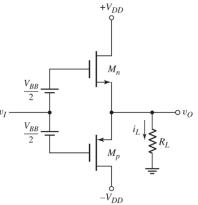
- 1. (10%) For a power MOSFET,  $\mathcal{O}_{dev-case} = 1.5 \circ C/W$ ,  $\mathcal{O}_{snk-amb} = 2.8 \circ C/W$ , and  $\mathcal{O}_{case-snk} = 0.6 \circ C/W$ . The ambient temperature is 25 °C.
  - (a) If the maximum junction temperature is limited to  $T_{j,\max} = 120 \circ C$ , determine the maximum allowed power dissipation.
  - (b) Using the results of part (a), determine the temperature of the case and heat sink.
- 2. (20%) For the common-emitter output stage shown on the right, let  $V_{CC}$  = 12 V and  $R_L$  = 1 k $\Omega$ . Assume the transistor *Q*-point is in the center of the load line.
  - (a) Determine the quiescent power dissipated in the transistor.
  - (b) Assume the sinusoidal output voltage is limited to a 9 V peak-topeak value. Determine
    - (i) the average signal power delivered to the load,
    - (ii) the power conversion efficiency, and
    - (iii) the average power dissipated in the transistor.
- 3. (15%) Consider the MOSFET class-AB output stage shown on the right. The circuit parameters are  $V_{DD} = 15$  V and  $R_L = 25\Omega$ . The transistors are matched with parameters K = 0.25 A/V<sup>2</sup> and  $|V_T| = 1.2$  V. The quiescent drain currents are to be 20 percent of the load current when  $v_O = 8$  V. Determine  $V_{BB}$ .

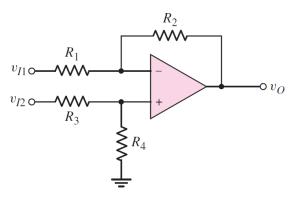




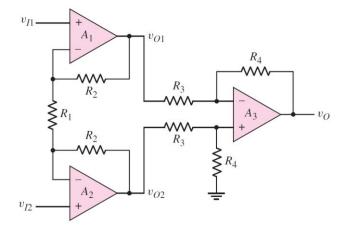




5. (15%) In the difference amplifier shown on the right,  $R_1 = R_3 = 10 \text{ k}\Omega$ ,  $R_2 = 20 \text{ k}\Omega$ , and  $R_4 = 21 \text{ k}\Omega$ . Determine the CMRR(dB).



6. (15%) Derive the output voltage  $v_0$  in terms of  $v_{I2} - v_{I1}$ .



7. (10%) What is the voltage gain  $v_0/v_1$ ?

